The MicroWriter ML® products are a range of photolithography machines designed for rapid prototyping and small volume manufacturing in R&D laboratories and clean rooms.

Conventional approaches to photolithography are usually based on exposing through a chromium-glass mask manufactured by specialist vendors. In R&D environments it is often necessary to change the mask design frequently. Direct-write lithography tools (also known as digital mask aligners or maskless aligners) overcome this problem by holding the mask in software. Rather than projecting light through a physical mask, direct-write lithography uses computer-controlled optics to project the exposure pattern directly onto the photoresist.

MicroWriter ML®3 Baby Plus is a compact, high-performance, low-cost direct-write optical lithography machine which is designed to offer unprecedented value for money in a small laboratory footprint. Measuring only 70cm x 60cm at its base, it sits on a standard laboratory bench or desk and plugs into a supplied laptop computer. Its only service requirement is a standard power socket. A light-excluding enclosure with safety interlock allows it to be used equally well in an open laboratory environment or in a clean room. Easy to use Windows® based software means most exposures can be set up and launched with just a few mouse clicks. Two different minimum feature sizes (1µm and 5µm) can be selected automatically via software. This allows non-critical parts of the exposure to be performed rapidly at 5µm minimum feature size while retaining high resolution writing for critical parts. The MicroWriter ML®3 Baby Plus also features an optical surface profilometer tool and an automated wafer inspection tool for examining fabricated structures.

Key features and specifications:

- 149mm x 149mm maximum writing area.
- 155mm x 155mm x 7mm maximum wafer size.
- 1µm and 5µm minimum feature sizes across full writing area.
- Automatic selection of resolution via software – no manual changing of lens required.
- 405nm long-life semiconductor lightsource suitable for broadband, g- and h-line positive and negative photoresists (e.g. S1800, ECI-3000, MiR 701). Replacement 385nm and 365nm lightsources available as option, suitable for g-, h- and i-line photoresists (e.g. SU-8).
- XY interferometer with 15nm resolution for precise motion control.
- Fast writing speed: up to 50mm²/minute (1µm minimum feature size) and 180mm²/minute (5µm minimum feature size), allowing a typical 50mm x 50mm area combining critical and non-critical areas to be exposed in under 30 minutes.
- Autofocus system using yellow light with real-time surface tracking laser—no minimum wafer size.
- High quality infinite conjugate optical microscope camera with x3 aspheric objective lens and x10 Olympus plan objective lens and yellow light illumination for alignment to lithographic markers on the wafer (±1µm 3σ alignment accuracy).
- Automatic changing between microscope magnifications via software – no manual changing of lens required. Additional x4 digital zoom can be selected in software.
- Grey scale exposure mode for 3-dimensional patterning (255 grey levels).
- Software API for external interfacing and control.
- 200nm minimum addressable grid; 15nm sample stage resolution.
- Acceptable file formats: CIF, GDS2, BMP, TIFF, JPEG, PNG, GIF.
- Automatic laser-based wafer centring tool.
- Built-in 2-dimensional optical surface profiler (200nm thickness resolution) for examining exposed resists, deposited layers, etching and other MEMS process steps.
- Automatic wafer inspection tool allowing each die on a wafer to be imaged.
- External dimensions: 700mm (w) x 700mm (d) x 700mm (h), excluding computer.
- Light-excluding enclosure with safety interlock.
- Designed for desktop use – no optical table required.
- Easy to use, Windows® based control software supplied.
- Supplied with KLayout open-source mask design software (www.klayout.de)
- Supplied with pre-configured 64-bit Windows® 10 PC and monitor for ‘plug and play’ installation.
- All cables supplied.
- Extremely competitively priced for University and industrial R&D budgets.
- Can be later upgraded to MicroWriter ML®3 Mesa or Pro for higher performance.
- CE-marked and compliant with EN-61010.
- 90-260 VAC, 50-60Hz, 4A single phase power requirement.

Designed for R&D in:
- Microelectronics and semiconductors
- Spintronics
- MEMS / NEMS
- Sensors
- Microfluidics and lab-on-a-chip
- Nanotechnology
- Materials science
- Graphene and other 2-dimensional materials

Examples of fabricated structures

Electrical transport measurement chip: MicroWriter ML®3 Baby Plus built-in optical microscope image of exposed AZ® ECI 3007 positive photoresist developed in AZ® 326 MIF developer (left); SEM images after metallization with 20nm of gold (centre and right). Square contact pads are 100µm wide; central wires are 3µm wide.

Micro-text: SEM images after metallization with 20nm of gold and lift-off. Lower case letters are 27µm high; gap between letters ‘r’ and ‘o’ is 1.5µm.
Microfluidic device: SEM images after metallization with 20nm of gold of AZ® 9260 12µm thick positive photoresist developed in AZ® 326 MIF developer.

Large area contact pads: SEM image after metallization with 20nm of gold and lift-off of four 660µm x 540µm contact pads exposed rapidly using 5µm minimum feature size.

MicroWriter ML®3 Baby Plus built-in optical microscope image (left) and 3D rendered MicroWriter ML®3 Baby Plus optical surface profilometer image (right) of 1.4µm thick patterned resist. Scale bar is 30µm.

Contact:
Durham Magneto Optics Ltd

www.durhammagnetooptics.com
E-mail: sales@durhammagnetooptics.com